

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/511,741	10/18/2004	Akio Iwabuchi	60233-012	4956
75	90 10/05/2005		EXAMINER	
Raymond E Scott			FENTY, JESSE A	
Howard & How	ard Attorneys		•	
The Pinehurst Office Center			ART UNIT	PAPER NUMBER
Suite #101 39400 Woodward Avenue			2815	
Bloomfield Hills, MI 48304-5151			DATE MAILED: 10/05/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

		<u> </u>		H,
		Application No.	Applicant(s)	
		10/511,741	IWABUCHI, AKIO	
	Office Action Summary	Examiner	Art Unit	
		Jesse A. Fenty	2815	
Period fo	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the	correspondence address	
A SHO WHIC - Exter after - If NO - Failui Any r	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DA asions of time may be available under the provisions of 37 CFR 1.15 SIX (6) MONTHS from the mailing date of this communication. period for reply is specified above, the maximum statutory period we re to reply within the set or extended period for reply will, by statute pely received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDON	DN. timely filed m the mailing date of this communication IED (35 U.S.C. § 133).	•
Status	patent term adjustment. See 57 GTK 1.704(b).			
1)⊠ 2a) <u></u>	Responsive to communication(s) filed on <u>18 O</u> This action is FINAL . 2b) This Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final. nce except for formal matters, p		s ,
Dispositi	on of Claims			
5)□ 6)⊠ 7)⊠ 8)□ Applicati 9)□ 10)□	Claim(s) 1-7 is/are pending in the application. 4a) Of the above claim(s) is/are withdray. Claim(s) is/are allowed. Claim(s) 1.2 and 7 is/are rejected. Claim(s) 3-6 is/are objected to. Claim(s) are subject to restriction and/o on Papers The specification is objected to by the Examine. The drawing(s) filed on is/are: a) accomplicant may not request that any objection to the Replacement drawing sheet(s) including the correct. The oath or declaration is objected to by the Examine.	r election requirement. r. epted or b) objected to by the drawing(s) be held in abeyance. Sion is required if the drawing(s) is c	ee 37 CFR 1.85(a). Objected to. See 37 CFR 1.121(d	d).
Priority u	inder 35 U.S.C. § 119			
12)⊠ <i>a</i>)[Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority document: 2. Certified copies of the priority document: 3. Copies of the certified copies of the priority document application from the International Bureausee the attached detailed Office action for a list	s have been received. s have been received in Applica rity documents have been recei u (PCT Rule 17.2(a)).	ation No ved in this National Stage	
2) 🔲 Notic 3) 🔯 Inforr	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) r No(s)/Mail Date 10/18/04.	4) Interview Summa Paper No(s)/Mail 5) Notice of Informal 6) Other:		

Application/Control Number: 10/511,741

Art Unit: 2815

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 1, 2 and 7 are rejected under 35 U.S.C. 102(e) as being anticipated by Watabe (U.S. Patent No. 6,642,599 B1).

In re claims 1 and 7, Watabe (esp. Fig. 1) discloses a semiconductor element and method of manufacturing the same, comprising:

first semiconductor region (1) of a first conductive type; a second semiconductor region (5) of a second conductive type which is formed on said first semiconductor region (1); a third semiconductor region (13) of a first conductive type which is formed in a predetermined surface area of said second semiconductor region (5); a fourth semiconductor region (11) of a first conductive type which is formed in a surface area of said third semiconductor region (13) and has a higher impurity concentration than said third semiconductor region (13) has; and a fifth semiconductor region (9) which is formed in a surface area of said second semiconductor region (5) so as to surround said third semiconductor region (13),

wherein:

said third semiconductor region (13) has a central portion which surrounds said fourth semiconductor region (11), and a peripheral portion (curved outer portions) which surrounds said central portion;

said central portion is formed to have a depth from a surface of said second semiconductor region (5) that is deeper than that of said peripheral portion; and

said second semiconductor region (5) arranged right under said central portion has a smaller amount of electric charges than an amount of electric charges of said second semiconductor region (5) arranged right under said peripheral portion, because said second semiconductor region (5) arranged right under said central portion has a thickness thinner than that of said second semiconductor region (3) arranged right under said peripheral portion.

In re claim 2, Watabe discloses the device of claim 1, further comprising: a drain electrode (53a) formed on said fourth semiconductor region (11); a source electrode (53b) formed on said fifth semiconductor region (9); a gate insulation film (19) covering said second semiconductor region (5) between said third semiconductor region (13) and said fifth semiconductor region (9); and a gate electrode (21a) formed on said gate insulation film.

Application/Control Number: 10/511,741

Art Unit: 2815

Allowable Subject Matter

Page 4

3. Claims 3-6 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

- 4. The following is a statement of reasons for the indication of allowable subject matter:
 - a. In re claim 3, the semiconductor device comprising where at least the second semiconductor region which is present right under the sixth semiconductor region has a same thickness as that of the second semiconductor region which is present right under the claimed peripheral portion.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jesse A. Fenty whose telephone number is 571-272-1729. The examiner can normally be reached on 5/4-9 1st Fri. Off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 571-272-1664. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Application/Control Number: 10/511,741

Art Unit: 2815

Page 5

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Examiner
Art Unit 2815